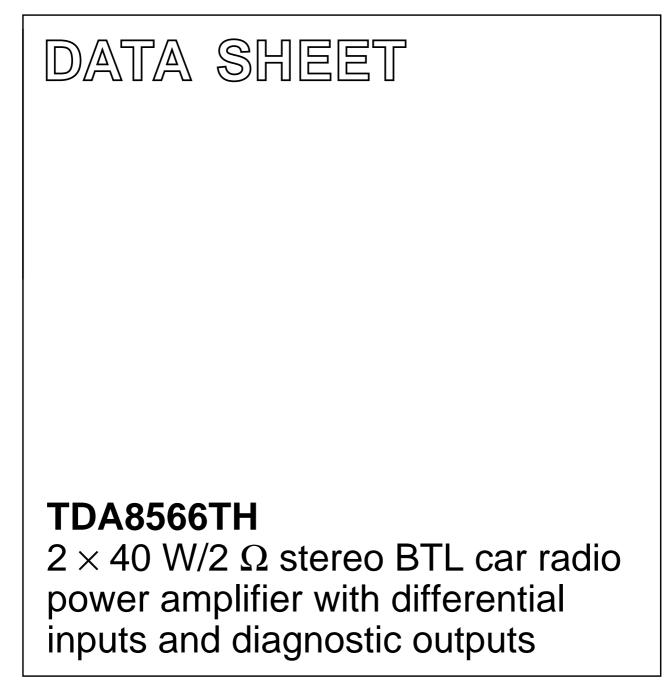
INTEGRATED CIRCUITS



Objective specification File under Integrated Circuits, IC01 2001 Apr 24



Objective specification

$\textbf{2}\times\textbf{40}$ W/2 Ω stereo BTL car radio power amplifier with differential inputs and diagnostic outputs

TDA8566TH

FEATURES

- Differential inputs
- Very high Common Mode Rejection Ratio (CMRR)
- High common mode input signal handling
- Requires very few external components
- High output power
- 4 and 2 Ω load driving capability
- Low offset voltage at output
- Fixed gain
- Diagnostic facility (distortion, short-circuit and temperature pre-warning)
- · Good ripple rejection
- Mode select switch (operating, mute and standby)
- Load dump protection
- Short-circuit proof to ground, to V_P and across the load

- Low power dissipation in any short-circuit condition
- Thermally protected
- Reverse polarity safe
- Protected against electrostatic discharge
- No switch-on/switch-off plops
- Low thermal resistance.

GENERAL DESCRIPTION

The TDA8566TH is an integrated class-B output amplifier contained in a 20-lead small outline plastic package. The device contains 2 amplifiers in a Bridge-Tied Load (BTL) configuration. The output power is 2×25 W in a 4 Ω load or 2×40 W in a 2 Ω load. It has a differential input stage and 2 diagnostic outputs. The device is primarily developed for car radio applications.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _P	operating supply voltage		6	14.4	18	V
I _{ORM}	repetitive peak output current		_	-	7.5	A
I _{q(tot)}	total quiescent current		_	115	-	mA
I _{stb}	standby current		_	0.1	10	μA
I _{sw}	switch-on current		_	-	40	μA
Zi	input impedance		100	120	-	kΩ
P _{out}	output power	$R_L = 4 \Omega$; THD = 10%	_	25	-	W
		$R_L = 2 \Omega$; THD = 10%	_	40	-	W
SVRR	supply voltage ripple rejection	R _s = 0 Ω	_	60	_	dB
α _{cs}	channel separation	R _s = 10 kΩ	_	50	-	dB
CMRR	common mode rejection ratio		_	75	-	dB
G _v	closed loop voltage gain		25	26	27	dB
V _{n(o)}	noise output voltage	R _s = 0 Ω	_	_	120	μV

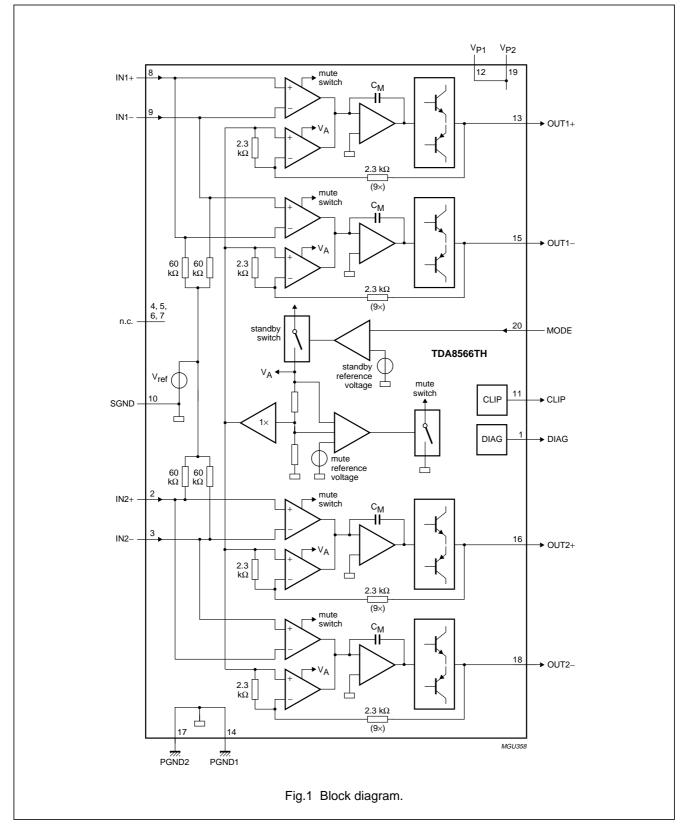
QUICK REFERENCE DATA

ORDERING INFORMATION

TYPE	PACKAGE			
NUMBER	NAME	DESCRIPTION	VERSION	
TDA8566TH	HSOP20	plastic, heatsink small outline package; 20 leads; low stand-off height	SOT418-2	

TDA8566TH

BLOCK DIAGRAM



PINNING

SYMBOL	PIN	DESCRIPTION
DIAG	1	short-circuit and temperature
		pre-warning diagnostic output
N2+	2	channel 2 input positive
IN2-	3	channel 2 input negative
n.c.	4	not connected
n.c.	5	not connected
n.c.	6	not connected
1.C.	7	not connected
N1+	8	channel 1 input positive
IN1–	9	channel 1 input negative
SGND	10	signal ground
CLIP	11	clip detection output
V _{P1}	12	supply voltage 1
OUT1+	13	channel 1 output positive
PGND1	14	power ground 1
OUT1-	15	channel 1 output negative
OUT2+	16	channel 2 output positive
PGND2	17	power ground 2
OUT2-	18	channel 2 output negative
V _{P2}	19	supply voltage 2
MODE	20	mode select switch input
		(standby/mute/operating)

TDA8566TH

TDA8566TH

2×40 W/2 Ω stereo BTL car radio power amplifier with differential inputs and diagnostic outputs

FUNCTIONAL DESCRIPTION

The TDA8566TH contains 2 identical amplifiers and can be used for BTL applications. The gain of each amplifier is fixed at 26 dB. Special features of this device are:

- 1. Mode select switch
- 2. Clip detection
- 3. Short-circuit diagnostic
- 4. Temperature pre-warning
- 5. Open-collector diagnostic outputs
- 6. Differential inputs.

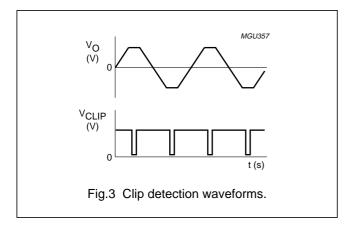
Mode select switch (pin MODE)

- Standby: low supply current
- Mute: input signal suppressed
- Operating: normal on condition.

Since this pin has a very low input current (<40 μ A), a low cost supply switch can be applied. To avoid switch-on plops, it is advisable to keep the amplifier in the mute mode for a period of \geq 150 ms (charging the input capacitors at pins IN1+, IN1–, IN2+ and IN2–). This can be realized by using a microcontroller or by using an external timing circuit as illustrated in Fig.7.

Clip detection (pin CLIP)

When clipping occurs at one or more output stages, the dynamic distortion detector becomes active and pin CLIP goes LOW. This information can be used to drive a sound processor or a DC volume control to attenuate the input signal and so limit the level of distortion. The output level of pin CLIP is independent of the number of channels that are being clipped. The clip detection circuit is disabled in a short-circuit condition, so if a fault condition occurs at the outputs, pin CLIP will remain at a HIGH level. The clip detection waveforms are illustrated in Fig.3.



Short-circuit diagnostic (pin DIAG)

When a short-circuit occurs at one or more outputs to ground or to the supply voltage, the output stages are switched off until the short-circuit is removed and the device is switched on again (with a delay of approximately 20 ms after the removal of the short-circuit). During this short-circuit condition, pin DIAG is continuously LOW.

When a short-circuit occurs across the load of one or both channels, the output stages are switched off for approximately 20 ms. After that time the load condition is checked during approximately 50 μ s to see whether the short-circuit is still present. Due to this duty cycle of 50 μ s/20 ms the average current consumption during the short-circuit condition is very low (approximately 40 mA). During this condition, pin DIAG is LOW for 20 ms and HIGH for 50 μ s; see Fig.4. The power dissipation in any short-circuit condition is very low.

Temperature pre-warning (pin DIAG)

When the junction temperature (T_{vj}) reaches 145 $^\circ\text{C},$ pin DIAG will become continuously LOW.

Open-collector diagnostic outputs

Pins DIAG and CLIP are open-collector outputs, therefore more devices can be tied together. Pins DIAG and CLIP can also be tied together. An external pull-up resistor is required.

Differential inputs

The input stage is a high-impedance fully differential balanced input stage that is also capable of operating in a single-ended mode with one of the inputs capacitively coupled to an audio ground. It should be noted that if a source resistance is added (input voltage dividers) the CMRR degrades to lower values.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _P	supply voltage	operating	_	18	V
		non-operating	-	30	V
		load dump protection; during 50 ms; $t_r \ge 2.5$ ms	-	45	V
I _{OSM}	non-repetitive peak output current		-	10	A
I _{ORM}	repetitive peak output current		-	7.5	A
T _{stg}	storage temperature		-55	+150	°C
T _{vj}	virtual junction temperature		_	150	°C
T _{amb}	ambient temperature		-40	+85	°C
V _{psc}	short-circuit safe voltage		_	18	V
V _{rp}	reverse polarity voltage		_	6.0	V
P _{tot}	total power dissipation		_	60	W

QUALITY SPECIFICATION

Quality specification in accordance with "SNW-FQ-611D", if this type is used as an audio amplifier.

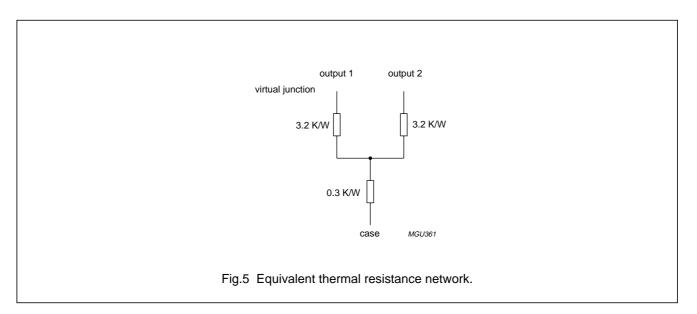
THERMAL CHARACTERISTICS

Thermal characteristics in accordance with IEC 60747-1.

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-c)}	thermal resistance from junction to case	see Fig.5	1.9	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	40	K/W

TDA8566TH

TDA8566TH



DC CHARACTERISTICS

 V_P = 14.4 V; T_{amb} = 25 °C; measured in test circuit of Fig.6; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply			•	-	-	
V _P	supply voltage	note 1	6	14.4	18	V
lq	quiescent current	$R_L = \infty$	-	115	180	mA
Operating	condition			•		•
V _{MODE}	mode select switch level		8.5	-	V _P	V
I _{MODE}	mode select switch current	V _{MODE} = 14.4 V	-	15	40	μA
Vo	output voltage	note 2	-	7.0	-	V
V _{OO}	output offset voltage		-	-	100	mV
Mute cond	lition					•
V _{MODE}	mode select switch level		3.3	-	6.4	V
Vo	output voltage	note 2	-	7.0	-	V
V _{OO}	output offset voltage		-	-	60	mV
ΔV_{OO}	output offset voltage difference	with respect to operating condition	-	-	60	mV
Standby c	ondition			•		•
V _{MODE}	mode select switch level		0	-	2	V
I _{stb}	standby current		-	0.1	10	μA
Diagnostic	; ;		•			·
V _{DIAG}	diagnostic output voltage	during any fault condition	_	_	0.6	V

Notes

1. The circuit is DC adjusted at V_P = 6 to 18 V and AC operating at V_P = 8.5 to 18 V.

2. At V_P = 18 to 30 V the DC output voltage is ≤ 0.5 V_P.

TDA8566TH

AC CHARACTERISTICS

 $V_P = 14.4 \text{ V}$; $T_{amb} = 25 \text{ °C}$; $R_L = 2 \Omega$; $f_i = 1 \text{ kHz}$; measured in test circuit of Fig.6; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Po	output power	THD = 0.5%	25	30	-	W
		THD = 10%	33	40	-	W
		THD = 30%	45	55	-	W
		V _P = 13.5 V; THD = 0.5%	_	25	_	W
		V _P = 13.5 V; THD = 10%	_	35	-	W
		THD = 0.5%; R_L = 4 Ω	16	19	-	W
		THD = 10%; $R_L = 4 \Omega$	21	25	_	W
		THD = 30%; $R_L = 4 \Omega$	28	35	-	W
		$V_{P} = 13.5 \text{ V}; \text{ THD} = 0.5\%;$ $R_{L} = 4 \Omega$	-	14	-	W
		$V_{P} = 13.5 \text{ V}; \text{ THD} = 10\%;$ $R_{L} = 4 \Omega$	-	22	-	W
THD	total harmonic distortion	$P_0 = 1 W$	-	0.1	-	%
		V _{CLIP} = 0.6 V; note 1	-	8	-	%
		$P_{o} = 1 \text{ W}; \text{ R}_{L} = 4 \Omega$	_	0.05	-	%
В	power bandwidth	THD = 0.5%; $P_o = -1 dB$ with respect to 25 W	-	20 to 20000	-	Hz
f _{ro(I)}	low frequency roll off	-1 dB; note 2	_	25	_	Hz
f _{ro(h)}	high frequency roll off	–1 dB	20	-	-	kHz
G _v	closed loop voltage gain		25	26	27	dB
SVRR	supply voltage ripple	operating; note 3	50	-	-	dB
	rejection	mute; note 3	50	-	-	dB
		standby; note 3	80	-	-	dB
Zi	input impedance	differential	100	120	150	kΩ
		single-ended	50	60	75	kΩ
$ \Delta Z_i $	input impedance mismatch		-	2	-	%
V _{n(o)}	noise output voltage	operating; $R_s = 0 \Omega$; note 4	_	85	120	μV
		operating; $R_s = 10 \text{ k}\Omega$; note 4	-	100	-	μV
		mute; independent of R _s ; note 4	_	60	-	μV
α _{cs}	channel separation	$P_0 = 25$ W; $R_s = 10$ kΩ	45	-	-	dB
$ \Delta G_v $	channel unbalance		-	_	1	dB

TDA8566TH

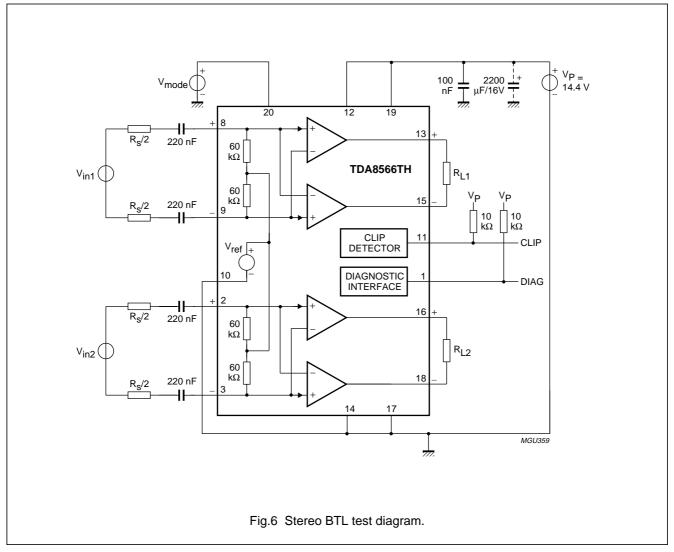
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{o(mute)}	output signal voltage in mute	$V_{in} = V_{in(max)} = 1 V (RMS)$	_	_	2	mV
CMRR	common mode rejection	$R_s = 0 \Omega$; note 5	60	75	_	dB
	ratio	$R_s = 45 \text{ k}\Omega$; note 6	40	_	_	dB

Notes

- 1. Dynamic distortion detector active; pin CLIP is LOW.
- 2. Frequency response externally fixed.
- 3. $V_{ripple} = V_{ripple(max)} = 2 V (p-p); R_s = 0 \Omega.$
- 4. Noise measured in a bandwidth of 20 Hz to 20 kHz.
- 5. Common mode rejection ratio measured at the output (over R_L) with both inputs tied together; $V_{common} \leq 3.5 \text{ V} \text{ (RMS)}$; f_i = 100 Hz to 10 kHz; R_s = 0 Ω .
- 6. Common mode rejection ratio measured at the output (over R_L) with both inputs tied together; $V_{common} \leq 3.5 \text{ V} \text{ (RMS)}; f_i = 1 \text{ kHz}; R_s = 45 \text{ k}\Omega$. The mismatch of the input coupling capacitors is excluded.

TDA8566TH

TEST AND APPLICATION INFORMATION



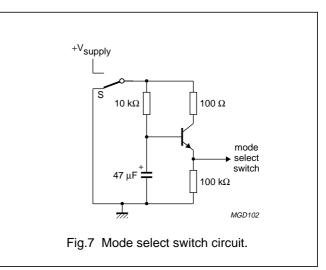
Application information

DIAGNOSTIC OUTPUT

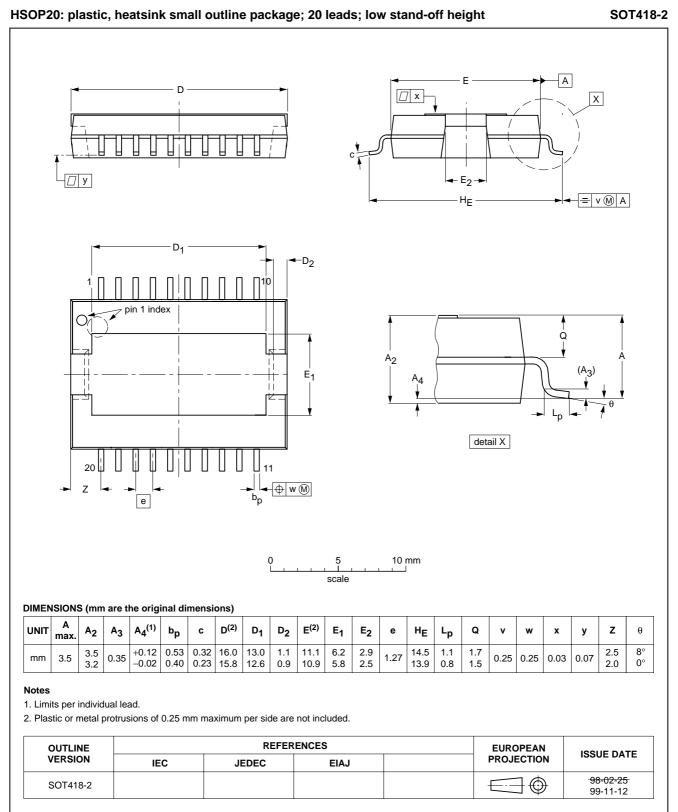
Special care must be taken in the PCB layout to separate pin CLIP from pins IN1+, IN1-, IN2+ and IN2- to minimize the crosstalk between the CLIP output and the inputs.

MODE SELECT SWITCH

To avoid switch-on plops, it is advisable to keep the amplifier in the mute mode during \geq 150 ms (charging of the input capacitors at pins IN1+, IN1–, IN2+ and IN2–). The circuit in Fig.7 slowly ramps-up the voltage at the mode select switch pin when switching on and results in fast muting when switching off.



PACKAGE OUTLINE



TDA8566TH

SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300 \,^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ\text{C}.$

TDA8566TH

Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD		
FACKAGE	WAVE	REFLOW ⁽¹⁾	
BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable	
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable ⁽²⁾	suitable	
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable	
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

TDA8566TH

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

TDA8566TH

NOTES

Philips Semiconductors – a worldwide company

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB, Argentina: see South America Tel. +31 40 27 82785, Fax. +31 40 27 88399 Australia: 3 Figtree Drive, HOMEBUSH, NSW 2140, New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND, Tel. +61 2 9704 8141, Fax. +61 2 9704 8139 Tel. +64 9 849 4160, Fax. +64 9 849 7811 Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Norway: Box 1, Manglerud 0612, OSLO. Tel. +43 1 60 101 1248. Fax. +43 1 60 101 1210 Tel. +47 22 74 8000, Fax. +47 22 74 8341 Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6, 220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773 Pakistan: see Singapore Belgium: see The Netherlands Philippines: Philips Semiconductors Philippines Inc., 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Brazil: see South America Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474 Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor, Poland: Al.Jerozolimskie 195 B, 02-222 WARSAW, 51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 68 9211, Fax. +359 2 68 9102 Tel. +48 22 5710 000, Fax. +48 22 5710 001 Portugal: see Spain Canada: PHILIPS SEMICONDUCTORS/COMPONENTS, Tel. +1 800 234 7381, Fax. +1 800 943 0087 Romania: see Italy China/Hong Kong: 501 Hong Kong Industrial Technology Centre, Russia: Philips Russia, UI. Usatcheva 35A, 119048 MOSCOW, 72 Tat Chee Avenue, Kowloon Tong, HONG KONG, Tel. +7 095 755 6918, Fax. +7 095 755 6919 Tel. +852 2319 7888, Fax. +852 2319 7700 Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762, Tel. +65 350 2538, Fax. +65 251 6500 Colombia: see South America Czech Republic: see Austria Slovakia: see Austria Denmark: Sydhavnsgade 23, 1780 COPENHAGEN V, Slovenia: see Italy Tel. +45 33 29 3333, Fax. +45 33 29 3905 South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale, Finland: Sinikalliontie 3, FIN-02630 ESPOO, 2092 JOHANNESBURG, P.O. Box 58088 Newville 2114, Tel. +358 9 615 800, Fax. +358 9 6158 0920 Tel. +27 11 471 5401, Fax. +27 11 471 5398 France: 7 - 9 Rue du Mont Valérien, BP317, 92156 SURESNES Cedex, South America: Al. Vicente Pinzon, 173, 6th floor, 04547-130 SÃO PAULO, SP, Brazil Tel. +33 1 4728 6600, Fax. +33 1 4728 6638 Tel. +55 11 821 2333. Fax. +55 11 821 2382 Germany: Hammerbrookstraße 69, D-20097 HAMBURG, Tel. +49 40 2353 60, Fax. +49 40 2353 6300 Spain: Balmes 22, 08007 BARCELONA Tel. +34 93 301 6312, Fax. +34 93 301 4107 Hungary: Philips Hungary Ltd., H-1119 Budapest, Fehervari ut 84/A, Tel: +36 1 382 1700, Fax: +36 1 382 1800 Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM, Tel. +46 8 5985 2000, Fax. +46 8 5985 2745 India: Philips INDIA Ltd, Band Box Building, 2nd floor, 254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025, Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH, Tel. +91 22 493 8541, Fax. +91 22 493 0966 Tel. +41 1 488 2741 Fax. +41 1 488 3263 Taiwan: Philips Semiconductors, 5F, No. 96, Chien Kuo N. Rd., Sec. 1, Indonesia: PT Philips Development Corporation, Semiconductors Division, Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510, TAIPEI, Taiwan Tel. +886 2 2134 2451, Fax. +886 2 2134 2874 Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080 Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd. Ireland: Newstead, Clonskeagh, DUBLIN 14, 60/14 MOO 11, Bangna Trad Road KM. 3, Bagna, BANGKOK 10260, Tel. +353 1 7640 000, Fax. +353 1 7640 200 Tel. +66 2 361 7910, Fax. +66 2 398 3447 Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053, Turkey: Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007 ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813 Italy: PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI), Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7, 252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461 Tel. +39 039 203 6838. Fax +39 039 203 6800 Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes, TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057 MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421 Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL, United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409, Tel. +82 2 709 1412, Fax. +82 2 709 1415 Tel. +1 800 234 7381, Fax. +1 800 943 0087 Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR, Uruguay: see South America Tel. +60 3 750 5214, Fax. +60 3 757 4880 Vietnam: see Singapore Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905, Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD, Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

Middle East: see Italy For all other countries apply to: Philips Semiconductors,

Marketing Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

© Philips Electronics N.V. 2001

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

753503/01/pp16

Date of release: 2001 Apr 24

Document order number: 9397 750 08125

SCA72

Let's make things better.

Internet: http://www.semiconductors.philips.com



Tel. +381 11 3341 299, Fax.+381 11 3342 553



